# NSN 5962-00-511-3890

Memory Microcircuit - Page 1 of 1



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#### **Body Length:**

Between 0.740 inches and 0.890 inches

#### **Body Width:**

Between 0.220 inches and 0.310 inches

#### **Body Height:**

Between 0.140 inches and 0.205 inches

#### **Maximum Power Dissipation Rating:**

625.0 milliwatts

#### **Operating Tempurature Range:**

+0.0/+70.0 degrees celsius

#### Storage Tempurature Range:

-55.0/+150.0 degrees celsius

#### **Features Provided:**

Monolithic and bipolar and w/enable and w/buffered output and w/decoded output and positive outputs and w/disable and programmed and

## programmable

Inclosure Material:

Plastic

#### Inclosure Configuration:

Dual-in-line

#### Output Logic Form:

Transistor-transistor logic

#### Input Circuit Pattern:

10 input

#### **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

5.5 volts power source

#### **Time Rating Per Chacteristic:**

50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Rom

#### Memory Capacity:

Unknown

#### **Terminal Type And Quantity:**

16 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

### Fiig:

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